NSN 5961-01-159-3339

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-159-3339 **Inclosure Material:** Ceramic **Overall Length:** 0.115 inches **Overall Diameter:** 0.235 inches **Internal Configuration:** Junction contact **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 560.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Leads and header gold **Precious Material:** Gold **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: